Diode Module

STARPOWER

SEMICONDUCTOR

FRED

FD200CCH40D3S

Molding Type Module

400V/200A in one-package



General Description

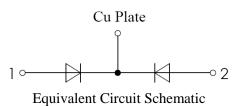
STARPOWER Diode Power Module provides low forward voltage as well as low reverse recovery loss. They are designed for the applications such as SMPS.

Features

- Fast soft diode
- Low forward voltage drop
- Small temperature coefficient
- Low reverse recovery losses
- High ruggedness
- Low inductance

Typical Applications

- SMPS
- PFC
- Electric welders
- DC choppers



Symbol	Description	FD200CCH40D3S	Units
V _{RRM}	Repetitive Peak Reverse Voltage	400	V
V _{RSM}	Non-repetitive Peak Reverse Voltage	400	V
I _{FAV}	Average Forward Current $T_c=100^{\circ}C$,Diode $T_c=100^{\circ}C$,Module	100 200	А
I _{FSM}	Surge Forward Current $V_R=0V_{,t_p}=10ms_{,T_j}=25^{\circ}C$ $V_R=0V_{,t_p}=8.3ms_{,T_j}=25^{\circ}C$	2000 2200	А
I ² t	I ² t-value $V_R=0V, t_p=10ms, T_j=25^{\circ}C$ $V_R=0V, t_p=8.3ms, T_j=25^{\circ}C$	20000 20166	A ² s
P _D	Maximum Power Dissipation @ T _i =175°C	698	W
Tj	Junction Temperature	-40 to +175	°C
T _{STG}	Storage Temperature Range	-40 to +125	°C
М	Terminal Connection Torque, Screw M6 Mounting Torque, Screw M6	3.0 to 4.7 3.0 to 4.7	N.m

Absolute Maximum Ratings $T_C=25$ °C unless otherwise noted

Electrical Characteristics of Diode $T_C=25$ °C unless otherwise noted

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units
$V_{\rm F}$	Diode Forward Voltage	I _F =100A	T _j =25℃		1.05	1.25	v
			T _j =125℃		0.95	1.15	
I _R	Diode Reverse Current V _R	V _V	Tj=25℃			0.5	mA
		V _R =V _{RRM}	T _j =125℃			1.0	
t _{rr}	Reverse Recovery Time	T _j =25℃		89		na	
		$I_F=100A$ $V_R=200V$ $di/dt=-200A/\mu s$	T _j =125℃		157		ns
I _{RM}	Peak Reverse Recovery Current		T _j =25℃		9.8		A
			T _j =125℃		18.4		
Qr	Reverse Recovery Charge	ui/ui- 2001 i/µ5	T _j =25℃		432		nC
			T _j =125℃		1449		

Thermal Characteristics

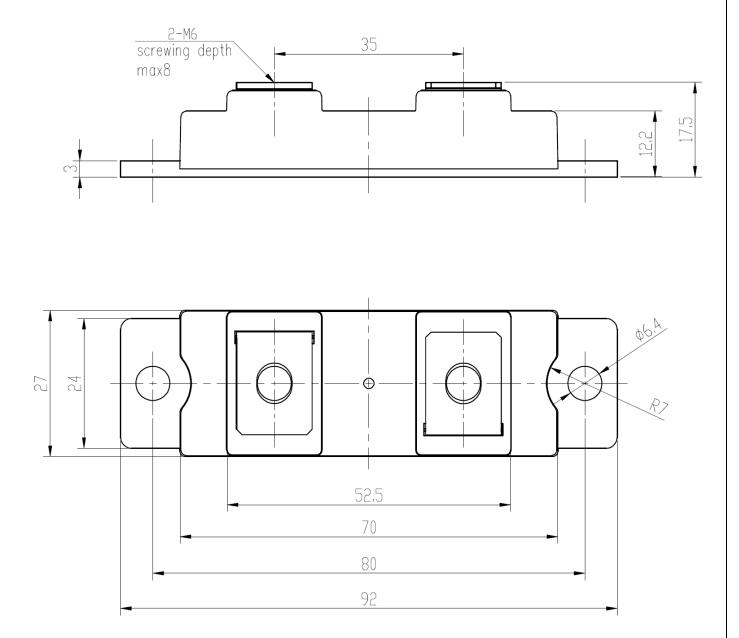
Symbol	Parameter	Тур.	Max.	Units
$R_{\theta JC}$	Junction-to-Case		0.215	K/W
$R_{\theta CS}$	Case-to-Sink (Conductive grease applied)	0.06		K/W
Weight	Weight of Module	95		g

FD200CCH40D3S

Diode Module

Package Dimensions

Dimensions in Millimeters



Terms and Conditions of Usage

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